BAS21HT1

Preferred Device

High Voltage Switching Diode

Features

• Pb-Free Packages are Available

MAXIMUM RATINGS

Symbol	Rating	Value	Unit	
V _R	V _R Continuous Reverse Voltage		Vdc	
V_{RRM}	Repetitive Peak Reverse Voltage	250	Vdc	
I _F	Peak Forward Current	200	mAdc	
I _{FM(surge)}	Peak Forward Surge Current	625	mAdc	

THERMAL CHARACTERISTICS

Symbol	Characteristic	Max	Unit
P_{D}	Total Device Dissipation FR-5 Board, (Note 1) T _A = 25°C	200	mW
	Derate above 25°C	1.57	mW/°C
$R_{ heta JA}$	Thermal Resistance, Junction-to-Ambient	635	°C/W
T _J , T _{stg}	Junction and Storage Temperature Range	-55 to +150	°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1. FR-5 Minimum Pad

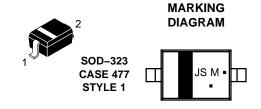


ON Semiconductor®

http://onsemi.com

HIGH VOLTAGE SWITCHING DIODE





JS = Device Code

M = Date Code*

Pb-Free Package

(Note: Microdot may be in either location)

*Date Code orientation may vary depending upon manufacturing location.

ORDERING INFORMATION

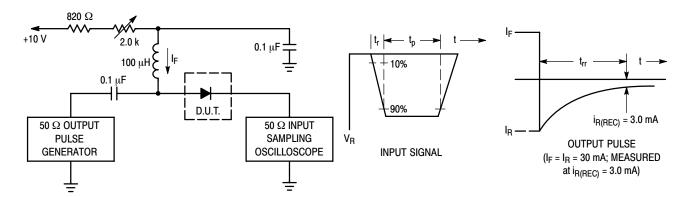
Device	Package	Shipping [†]
BAS21HT1	SOD-323	3000/Tape & Reel
BAS21HT1G	SOD-323 (Pb-Free)	3000/Tape & Reel
BAS21HT3	SOD-323	10,000/Tape & Reel
BAS21HT3G	SOD-323 (Pb-Free)	10,000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

Preferred devices are recommended choices for future use and best overall value.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Reverse Voltage Leakage Current $(V_R = 200 \text{ Vdc})$ $(V_R = 200 \text{ Vdc}, T_J = 150^{\circ}\text{C})$	I _R	-	0.1 100	μAdc
Reverse Breakdown Voltage (I _{BR} = 100 μAdc)	V _(BR)	250	-	Vdc
Forward Voltage (I _F = 100 mAdc) (I _F = 200 mAdc)	V _F	- -	1000 1250	mV
Diode Capacitance (V _R = 0, f = 1.0 MHz)	C _D	-	5.0	pF
Reverse Recovery Time $(I_F = I_R = 30 \text{ mAdc}, R_L = 100 \Omega)$	t _{rr}	-	50	ns



Notes: 1. A 2.0 k Ω variable resistor adjusted for a Forward Current (I_F) of 30 mA.

- 2. Input pulse is adjusted so I_{R(peak)} is equal to 30 mA.
- 3. $t_p \gg t_{rr}$

Figure 1. Recovery Time Equivalent Test Circuit

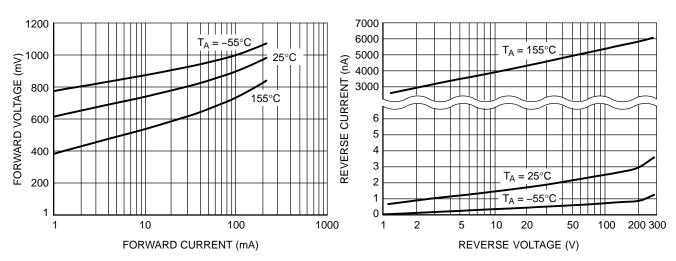


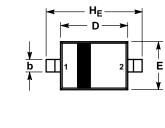
Figure 2. Forward Voltage

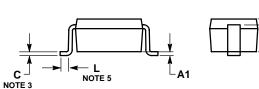
Figure 3. Reverse Leakage

BAS21HT1

PACKAGE DIMENSIONS

SOD-323 PLASTIC PACKAGE CASE 477-02 ISSUE G





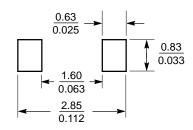
NOTES

- DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1982. CONTROLLING DIMENSION: MILLIMETERS.
- 3. LEAD THICKNESS SPECIFIED PER LIF DRAWING WITH SOLDER PLATING.
 4. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.
- DIMENSION L IS MEASURED FROM END OF RADIUS.

	MIL	LIMETE	ERS	INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.80	0.90	1.00	0.031	0.035	0.040
A1	0.00	0.05	0.10	0.000	0.002	0.004
A3	0.15 REF			0.006 REF		
b	0.25	0.32	0.4	0.010	0.012	0.016
С	0.089	0.12	0.177	0.003	0.005	0.007
D	1.60	1.70	1.80	0.062	0.066	0.070
Е	1.15	1.25	1.35	0.045	0.049	0.053
Ĺ	0.08			0.003		
HE	2.30	2.50	2.70	0.090	0.098	0.105

STYLE 1: PIN 1. CATHODE 2. ANODE

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D

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